



## **SPECIFICATION**

• Supplier : Samsung electro-mechanics • Samsung P/N : CL03A103KQ3NNNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 10nF, 6.3V, ±10%, X5R, 0201

## A. Samsung Part Number

<u>CL</u> <u>03</u> <u>A</u> <u>103</u> <u>K</u> <u>Q</u> <u>3</u> <u>N</u> <u>N</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

1	Series	Samsung Multi-layer Ceramic Capacitor		
2	Size	0201 (inch code)	L: 0.6 ± 0.03 mm	W: 0.3 ± 0.03 mm
3	Dielectric	X5R	8 Inner electrode	Ni
4	Capacitance	<b>10</b> nF	Termination	Cu
(5)	Capacitance	±10 %	Plating	Sn 100% (Pb Free)
	tolerance		Product	Normal
6	Rated Voltage	6.3 V	Special	Reserved for future use
7	Thickness	$0.3 \pm 0.03 \text{ mm}$	① Packaging	Cardboard Type,7"reel(10,000ea)

## **B. Samsung Reliability Test and Judgement condition**

	Performance	Test condition		
Capacitance	Within specified tolerance	1kHz±10% 1.0±0.2Vrms		
Tan δ (DF)	0.09 max.			
Insulation	More than 100Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.		
Resistance				
Appearance	No abnormal exterior appearance	Visual inspection		
Withstanding	No dielectric breakdown or	250% of the rated voltage		
Voltage	mechanical breakdown			
Temperature X5R				
Characteristics	(From -55℃ to 85℃, Capacitance change should be within ±15%)			
Adhesive Strength	No peeling shall be occur on the	200g·F, for 10±1 sec.		
of Termination	terminal electrode			
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)		
		with 1.0mm/sec.		
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder		
	is to be soldered newly	245±5°C, 3±0.3sec.		
		(preheating : 80~120 ℃ for 10~30sec.)		
Pacietanae to	Canacitanas change : within 17.5%	Solder not : 270   5°   10   10   2		
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.		
Soldering heat	Tan δ, IR : initial spec.			

	Performance	Test condition
Vibration Test	Capacitance change: within ±5%	Amplitude : 1.5mm
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)
		2hours × 3 direction (x, y, z)
Moisture	Capacitance change: within ±12.5%	With rated voltage
Resistance	Tan δ : 0.125 max	40±2℃, 90~95%RH, 500+12/-0 hour
	IR : More than 25MΩ·μF	
High Temperature	Capacitance change : within ±12.5%	With 200% of the rated voltage
Resistance	Tan δ : 0.125 max	Max. operating temperature
	IR : More than 50MΩ·μF	
		1000+48/-0 hour
Temperature	Capacitance change: within ±7.5%	1 cycle condition
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25°C
		→ Max. operating temperature → 25°C
		5 cycles test

## C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260+0/-5  $^{\circ}\text{C}$  , 10sec. Max )

<sup>\*</sup> For the more detail Specification, Please refer to the Samsung MLCC catalogue.